74LVC1G3157

10 Ω single-pole double-throw analog switch

Rev. 11 — 23 August 2023

Product data sheet

1. General description

The 74LVC1G3157 is a single-pole double-throw analog switch with a digital select input (S), two independent inputs/outputs (Y0 and Y1) and a common input/output (Z). Control inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

Schmitt-trigger action at control inputs makes the circuit tolerant of slower input rise and fall times.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- · Very low ON resistance:
 - 7.5 Ω (typical) at V_{CC} = 2.7 V
 - 6.5 Ω (typical) at V_{CC} = 3.3 V
 - 6 Ω (typical) at V_{CC} = 5 V
- 32 mA continuous switch current
- · Break-before-make switching
- · High noise immunity
- CMOS low power dissipation
- TTL interface compatibility at 3.3 V
- · Latch-up performance meets requirements of JESD 78 Class I
- Overvoltage tolerant control inputs to 5.5 V
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



10 Ω single-pole double-throw analog switch

3. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74LVC1G3157GW	-40 °C to +125 °C	TSSOP6	plastic thin shrink small outline package; 6 leads; body width 1.25 mm	SOT363-2				
74LVC1G3157GV	-40 °C to +125 °C	SC-74; TSOP6	plastic surface-mounted package; 6 leads	<u>SOT457</u>				
74LVC1G3157GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	<u>SOT886</u>				
74LVC1G3157GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	<u>SOT1115</u>				
74LVC1G3157GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202				
74LVC1G3157GX	-40 °C to +125 °C	X2SON6	plastic thermal enhanced extremely thin small outline package; no leads; 6 terminals; body 1.0 × 0.8 × 0.32 mm	SOT1255-2				

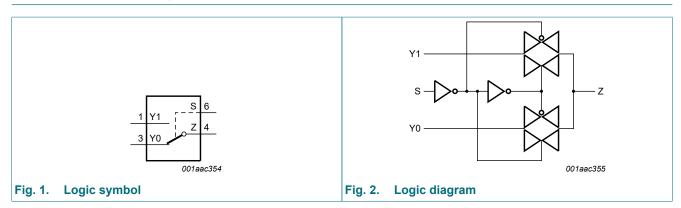
4. Marking

Table 2. Marking

Type number	Marking code[1]
74LVC1G3157GW	YJ
74LVC1G3157GV	YJ
74LVC1G3157GM	YJ
74LVC1G3157GN	YJ
74LVC1G3157GS	YJ
74LVC1G3157GX	YJ

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

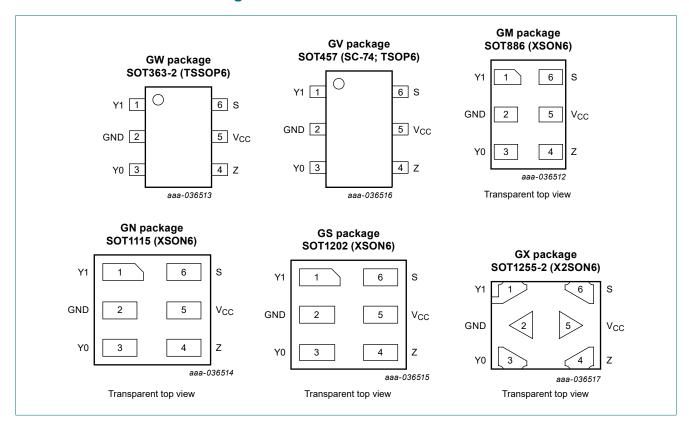
5. Functional diagram



10 Ω single-pole double-throw analog switch

6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
Y1	1	independent input or output
GND	2	ground (0 V)
Y0	3	independent input or output
Z	4	common output or input
V _{CC}	5	supply voltage
S	6	select input

7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

Input S	Channel on
L	Y0
Н	Y1

74LVC1G3157

10 Ω single-pole double-throw analog switch

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+6.5	V
VI	input voltage	[1]	-0.5	+6.5	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-50	-	mA
I _{SK}	switch clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±50	mΑ
V _{SW}	switch voltage	enable and disable mode [2]	-0.5	V _{CC} + 0.5	V
I _{SW}	switch current	V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V	-	±50	mΑ
I _{CC}	supply current		-	100	mΑ
I _{GND}	ground current		-100	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [3]	-	250	mW

- [1] The minimum input voltage rating may be exceeded if the input current rating is observed.
- [2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.
- [3] For SOT363-2 (TSSOP6) package: P_{tot} derates linearly with 3.7 mW/K above 83 °C.
 - For SOT457 (SC-74; TSOP6) package: Ptot derates linearly with 4.1 mW/K above 89 °C.
 - For SOT886 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.
 - For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.
 - For SOT1202 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.
 - For SOT1255-2 (X2SON6) package: Ptot derates linearly with 3.3 mW/K above 75 °C.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
V_{SW}	switch voltage	enable and disable mode [1]	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 1.65 V to 2.7 V [2]	-	-	20	ns/V
		V _{CC} = 2.7 V to 5.5 V [2]	-	-	10	ns/V

^[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

10 Ω single-pole double-throw analog switch

10. Static characteristics

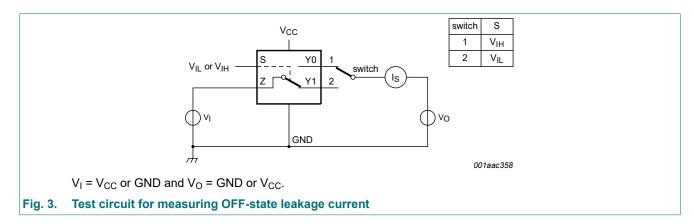
Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
				Min	Typ [1]	Max	Min	Max	
V _{IH}	HIGH-level input	V _{CC} = 1.65 V to 1.95 V		0.65 × V _{CC}	-	-	0.65 × V _{CC}	-	V
	voltage	V _{CC} = 2.3 V to 2.7 V		1.7	-	-	1.7	-	V
		V _{CC} = 3 V to 3.6 V		2.0	-	-	2.0	-	٧
		V _{CC} = 4.5 V to 5.5 V		0.7 × V _{CC}	-	-	0.7 × V _{CC}	-	V
V _{IL}	LOW-level input	V _{CC} = 1.65 V to 1.95 V		-	-	0.35 × V _{CC}	-	0.35 × V _{CC}	V
	voltage	V _{CC} = 2.3 V to 2.7 V		-	-	0.7	-	0.7	V
		V _{CC} = 3 V to 3.6 V		-	-	0.8	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V		-	-	0.3 × V _{CC}		0.3 × V _{CC}	V
I _I	input leakage current	pin S; V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	[2]	-	±0.1	±1	-	±1	μΑ
I _{S(OFF)}	OFF-state leakage current	V _{CC} = 5.5 V; see <u>Fig. 3</u>	[2]	-	±0.1	±0.2	-	±0.5	μΑ
I _{S(ON)}	ON-state leakage current	V _{CC} = 5.5 V; see <u>Fig. 4</u>	[2]	-	±0.1	±1	-	±2	μΑ
I _{CC}	supply current	V_I = 5.5 V or GND; V_{SW} = GND or V_{CC} ; V_{CC} = 1.65 V to 5.5 V	[2]	-	0.1	4	-	4	μΑ
ΔI _{CC}	additional supply current	pin S; $V_I = V_{CC} - 0.6 \text{ V}$; $V_{CC} = 5.5 \text{ V}$; $V_{SW} = \text{GND or } V_{CC}$	[2]	-	5	500	-	500	μΑ
Cı	input capacitance			-	2.5	-	-	-	pF
C _{S(OFF)}	OFF-state capacitance			-	6.0	-	-	-	pF
C _{S(ON)}	ON-state capacitance			-	18	-	-	-	pF

^[1] Typical values are measured at T_{amb} = 25 °C.

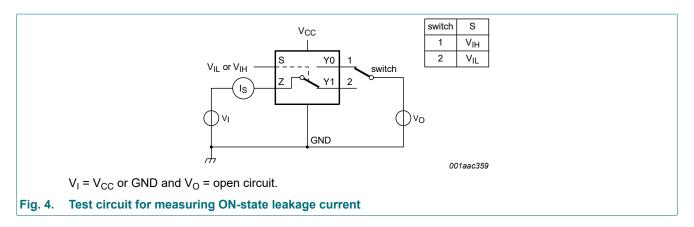
10.1. Test circuits



74LVC1G3157

^[2] These typical values are measured at V_{CC} = 3.3 V.

10 Ω single-pole double-throw analog switch



10.2. ON resistance

Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground 0 V); for graphs see Fig. 6 to Fig. 11.

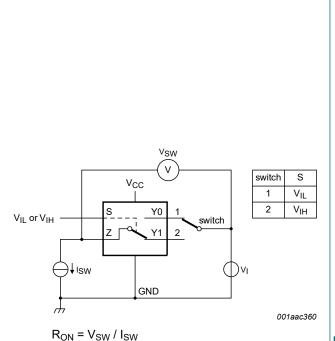
Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	Unit	
			Min	Typ [1]	Max	Min	Max	
R _{ON(peak)}	ON resistance	V _I = GND to V _{CC} ; see <u>Fig. 5</u>						
	(peak)	I _{SW} = 4 mA; V _{CC} = 1.65 V to 1.95 V	-	34.0	130	-	195	Ω
		I _{SW} = 8 mA; V _{CC} = 2.3 V to 2.7 V	-	12.0	30	-	45	Ω
		I _{SW} = 12 mA; V _{CC} = 2.7 V	-	10.4	25	-	38	Ω
		I _{SW} = 24 mA; V _{CC} = 3 V to 3.6 V	-	7.8	20	-	30	Ω
		I _{SW} = 32 mA; V _{CC} = 4.5 V to 5.5 V	-	6.2	15	-	23	Ω
O14(1411)	ON resistance	V _I = GND; see <u>Fig. 5</u>						
	(rail)	I_{SW} = 4 mA; V_{CC} = 1.65 V to 1.95 V	-	8.2	18	-	27	Ω
		I_{SW} = 8 mA; V_{CC} = 2.3 V to 2.7 V	-	7.1	16	-	24	Ω
		I _{SW} = 12 mA; V _{CC} = 2.7 V	-	6.9	14	-	21	Ω
		I _{SW} = 24 mA; V _{CC} = 3 V to 3.6 V	-	6.5	12	-	18	Ω
		I _{SW} = 32 mA; V _{CC} = 4.5 V to 5.5 V	-	5.8	10	-	15	Ω
		V _I = V _{CC} ; see <u>Fig. 5</u>						
		I_{SW} = 4 mA; V_{CC} = 1.65 V to 1.95 V	-	10.4	30	-	45	Ω
		I _{SW} = 8 mA; V _{CC} = 2.3 V to 2.7 V	-	7.6	20	-	30	Ω
		I _{SW} = 12 mA; V _{CC} = 2.7 V	-	7.0	18	-	27	Ω
		I _{SW} = 24 mA; V _{CC} = 3 V to 3.6 V	-	6.1	15	-	23	Ω
		I_{SW} = 32 mA; V_{CC} = 4.5 V to 5.5 V	-	4.9	10	-	15	Ω
R _{ON(flat)}	ON resistance	$V_I = GND \text{ to } V_{CC}$ [2]]					
	(flatness)	I_{SW} = 4 mA; V_{CC} = 1.65 V to 1.95 V	-	26.0	-	-	-	Ω
		I_{SW} = 8 mA; V_{CC} = 2.3 V to 2.7 V	-	5.0	-	-	-	Ω
		I _{SW} = 12 mA; V _{CC} = 2.7 V	-	3.5	-	-	-	Ω
		I _{SW} = 24 mA; V _{CC} = 3 V to 3.6 V	-	2.0	-	-	-	Ω
		I _{SW} = 32 mA; V _{CC} = 4.5 V to 5.5 V	-	1.5	-	-	-	Ω

74LVC1G3157

Typical values are measured at T_{amb} = 25 °C and nominal V_{CC} . Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

10 Ω single-pole double-throw analog switch

10.3. ON resistance test circuit and graphs



Test circuit for measuring ON resistance Fig. 5.

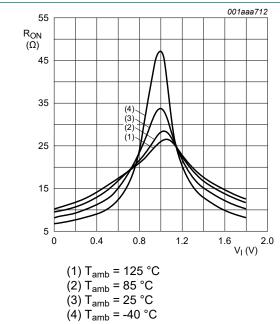
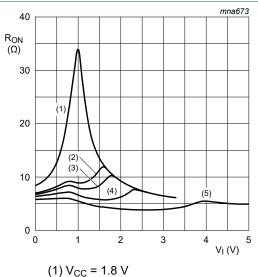


Fig. 7. ON resistance as a function of input voltage; $V_{CC} = 1.8 \text{ V}$

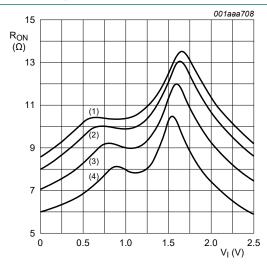


 $(2) V_{CC} = 2.5 V$

 $(3) V_{CC} = 2.7 V$ $(4) V_{CC} = 3.3 V$

 $(5) V_{CC} = 5.0 V$

Fig. 6. Typical ON resistance as a function of input voltage; T_{amb} = 25 °C



(1) T_{amb} = 125 °C

(2) T_{amb} = 85 °C

(3) $T_{amb} = 25 \,^{\circ}\text{C}$ (4) $T_{amb} = -40 \,^{\circ}\text{C}$

Fig. 8. ON resistance as a function of input voltage; $V_{CC} = 2.5 V$

10 Ω single-pole double-throw analog switch

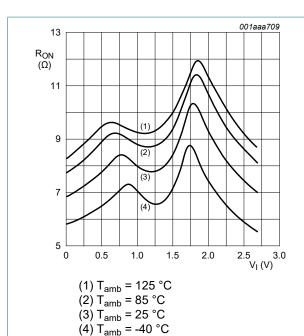
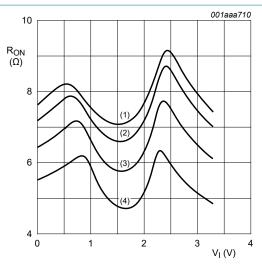


Fig. 9. ON resistance as a function of input voltage; $V_{CC} = 2.7 \text{ V}$



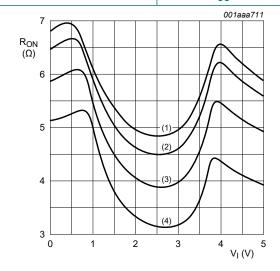
(1) $T_{amb} = 125 \, ^{\circ}C$

(2) $T_{amb} = 85 \, ^{\circ}C$

(3) $T_{amb} = 25 \, ^{\circ}C$

(4) $T_{amb} = -40 \, ^{\circ}C$

Fig. 10. ON resistance as a function of input voltage; $V_{CC} = 3.3 \text{ V}$



(1) $T_{amb} = 125 \, ^{\circ}C$

(2) $T_{amb} = 85 \, ^{\circ}C$

(3) $T_{amb} = 25 \, ^{\circ}C$

(4) $T_{amb} = -40 \, ^{\circ}C$

Fig. 11. ON resistance as a function of input voltage; $V_{CC} = 5.0 \text{ V}$

10 Ω single-pole double-throw analog switch

11. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 15.

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	-40 °C to	Unit	
				Min	Typ [1]	Max	Min	Max	
t _{pd}	propagation	Z to Yn or Yn to Z; see Fig. 12	[2] [3]						
	delay	V _{CC} = 1.65 V to 1.95 V		-	-	2	-	3.0	ns
		V _{CC} = 2.3 V to 2.7 V		-	-	1.2	-	2.0	ns
		V _{CC} = 2.7 V		-	-	1.0	-	1.5	ns
		V _{CC} = 3 V to 3.6 V		-	-	0.8	-	1.5	ns
		V _{CC} = 4.5 V to 5.5 V		-	-	0.6	-	1.0	ns
t _{en}	enable time	S to Yn; see Fig. 13	[4]						
		V _{CC} = 1.65 V to 1.95 V		3.1	8.7	20.8	3.1	22.0	ns
		V _{CC} = 2.3 V to 2.7 V		2.2	5.3	11.5	2.2	12.5	ns
		V _{CC} = 2.7 V		2.1	4.9	9.3	2.1	10.2	ns
		V _{CC} = 3 V to 3.6 V		1.8	4.0	7.6	1.8	9.0	ns
		V _{CC} = 4.5 V to 5.5 V		1.5	3.0	5.7	1.5	6.1	ns
t _{dis}	disable time	S to Yn; see Fig. 13	[5]						
		V _{CC} = 1.65 V to 1.95 V		3.0	6.0	11.4	3.0	11.7	ns
		V _{CC} = 2.3 V to 2.7 V		2.1	4.4	7.3	2.1	7.6	ns
		V _{CC} = 2.7 V		2.1	4.2	6.3	2.1	6.6	ns
		V _{CC} = 3 V to 3.6 V		1.7	3.6	5.3	1.7	5.9	ns
		V _{CC} = 4.5 V to 5.5 V		1.3	2.9	3.8	1.3	4.3	ns
t _{b-m}	break-before-	see <u>Fig. 14</u>	[6]						
	make time	V _{CC} = 1.65 V to 1.95 V		0.5	-	-	0.5	-	ns
		V _{CC} = 2.3 V to 2.7 V		0.5	-	-	0.5	-	ns
		V _{CC} = 2.7 V		0.5	-	-	0.5	-	ns
		V _{CC} = 3 V to 3.6 V		0.5	-	-	0.5	-	ns
		V _{CC} = 4.5 V to 5.5 V		0.5	-	-	0.5	-	ns

Typical values are measured at T_{amb} = 25 °C and nominal V_{CC}.

t_{pd} is the same as t_{PLH} and t_{PHL}.

Propagation delay is the calculated RC time constant of the typical ON resistance of the switch and the specified capacitance when driven by an ideal voltage source (zero output impedance).

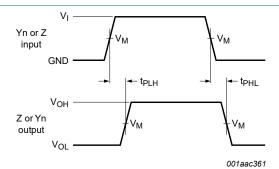
 t_{en} is the same as t_{PZH} and $t_{\text{PZL}}.$

t_{dis} is the same as t_{PLZ} and t_{PHZ}.

Break-before-make specified by design.

10 Ω single-pole double-throw analog switch

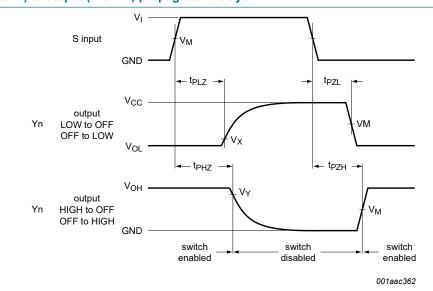
11.1. Waveforms and test circuits



Measurement points are given in Table 10.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 12. Input (Yn or Z) to output (Z or Yn) propagation delays



Measurement points are given in $\underline{\text{Table 10}}$.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 13. Enable and disable times

Table 10. Measurement points

Supply voltage	Input	Output	Output					
V _{CC}	V _M	V _M	V _X	V _Y				
1.65 V to 5.5 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{OL} + 0.3 V	V _{OH} - 0.3 V				

10 Ω single-pole double-throw analog switch

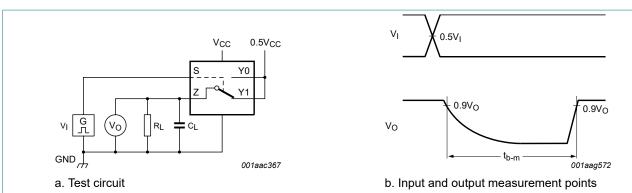
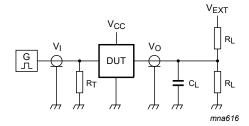


Fig. 14. Test circuit for measuring break-before-make timing



Test data is given in Table 11.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator;

C_L = Load capacitance including jig and probe capacitance;

R_L = Load resistance;

V_{EXT} = External voltage for measuring switching times.

Fig. 15. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Input		Load		V _{EXT}		
V _{CC}	V _I	t _r , t _f	CL	R _L	t _{PLH,} t _{PHL}	t _{PZH,} t _{PHZ}	t _{PZL,} t _{PLZ}
1.65 V to 1.95 V	V _{CC}	≤ 2.0 ns	50 pF	500 Ω	open	GND	2 × V _{CC}
2.3 V to 2.7 V	V _{CC}	≤ 2.0 ns	50 pF	500 Ω	open	GND	2 × V _{CC}
2.7 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open	GND	2 × V _{CC}
3 V to 3.6 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open	GND	2 × V _{CC}
4.5 V to 5.5 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open	GND	2 × V _{CC}

10 Ω single-pole double-throw analog switch

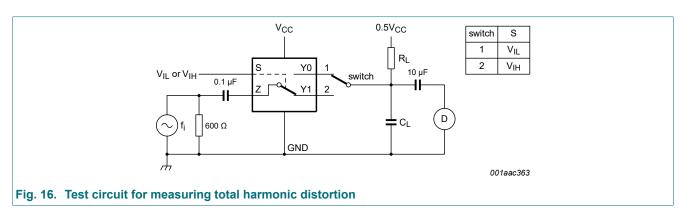
11.2. Additional dynamic characteristics

Table 12. Additional dynamic characteristics

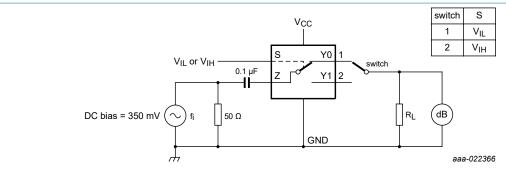
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); T_{amb} = 25 °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
THD	total harmonic distortion	f_i = 600 Hz to 20 kHz; R_L = 600 Ω; C_L = 50 pF; V_I = 0.5 V (p-p); see Fig. 16				
		V _{CC} = 1.65 V	-	0.260	-	%
		V _{CC} = 2.3 V	-	0.078	-	%
		V _{CC} = 3.0 V	-	0.078	-	%
		V _{CC} = 4.5 V	_	0.078	-	%
f _(-3dB)	-3 dB frequency response	R _L = 50 Ω; see <u>Fig. 17</u>				
		V _{CC} = 1.65 V	-	200	-	MHz
		V _{CC} = 2.3 V	-	300	-	MHz
		V _{CC} = 3.0 V	-	300	-	MHz
		V _{CC} = 4.5 V	-	300	-	MHz
α_{iso}	isolation (OFF-state)	R_L = 50 Ω; C_L = 5 pF; f_i = 10 MHz; see <u>Fig. 18</u>				
		V _{CC} = 1.65 V	-	-42	-	dB
		V _{CC} = 2.3 V	-	-42	-	dB
		V _{CC} = 3.0 V	-	-40	-	dB
		V _{CC} = 4.5 V	-	-40	-	dB
Q _{inj}	charge injection	C_L = 0.1 nF; V_{gen} = 0 V; R_{gen} = 0 Ω ; f_i = 1 MHz; R_L = 1 M Ω ; see Fig. 19				
		V _{CC} = 1.8 V	-	3.3	-	рС
		V _{CC} = 2.5 V	-	4.1	-	рС
		V _{CC} = 3.3 V	-	5.0	-	рС
		V _{CC} = 4.5 V	-	6.4	-	рС
		V _{CC} = 5.5 V	-	7.5	-	рС
	1					

11.3. Test circuits

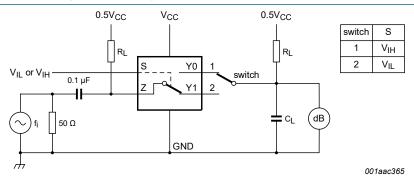


10 Ω single-pole double-throw analog switch



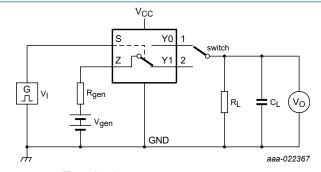
Adjust fi voltage to obtain 0 dBm level at output. Increase fi frequency until dB meter reads -3 dB.

Fig. 17. Test circuit for measuring the frequency response when switch is in ON-state



Adjust fi voltage to obtain 0 dBm level at input.

Fig. 18. Test circuit for measuring isolation (OFF-state)



a. Test circuit

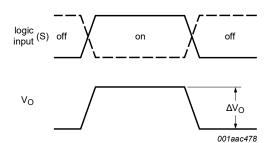
 $Q_{inj} = \Delta V_O \times C_L;$

 ΔV_O = output voltage variation;

R_{gen} = generator resistance;

 V_{gen} = generator voltage.

Fig. 19. Test circuit for measuring charge injection



b. Input and output pulse definitions

10 Ω single-pole double-throw analog switch

12. Package outline

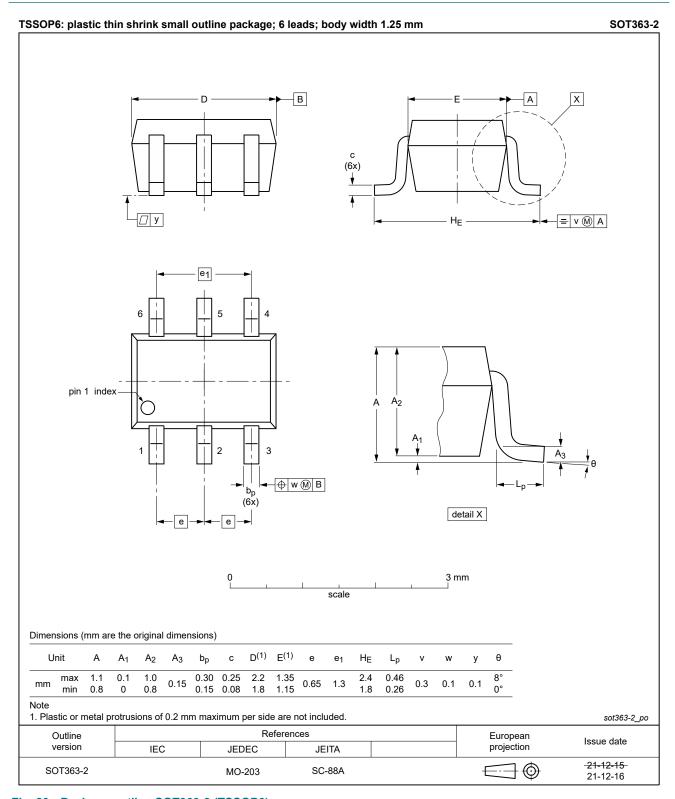


Fig. 20. Package outline SOT363-2 (TSSOP6)

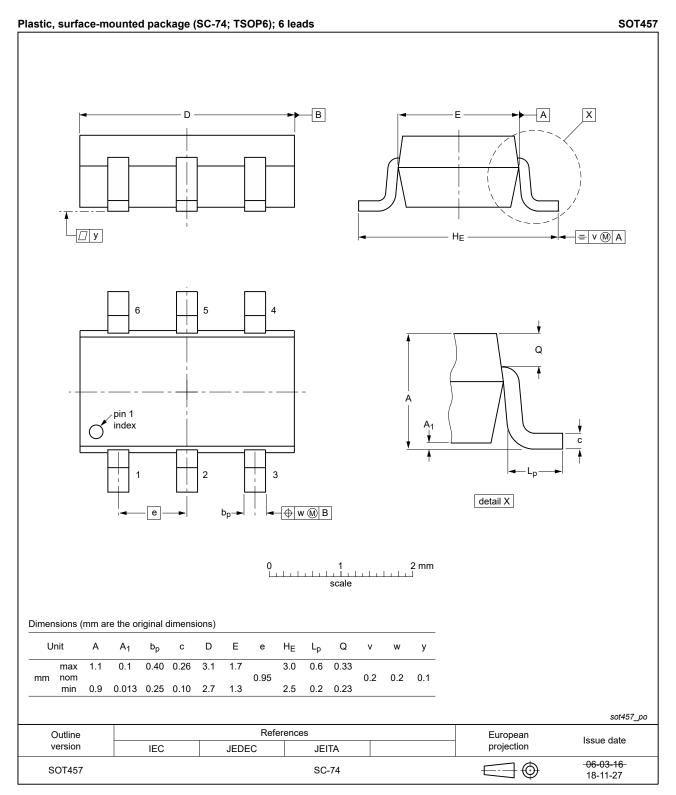


Fig. 21. Package outline SOT457 (SC-74; TSOP6)

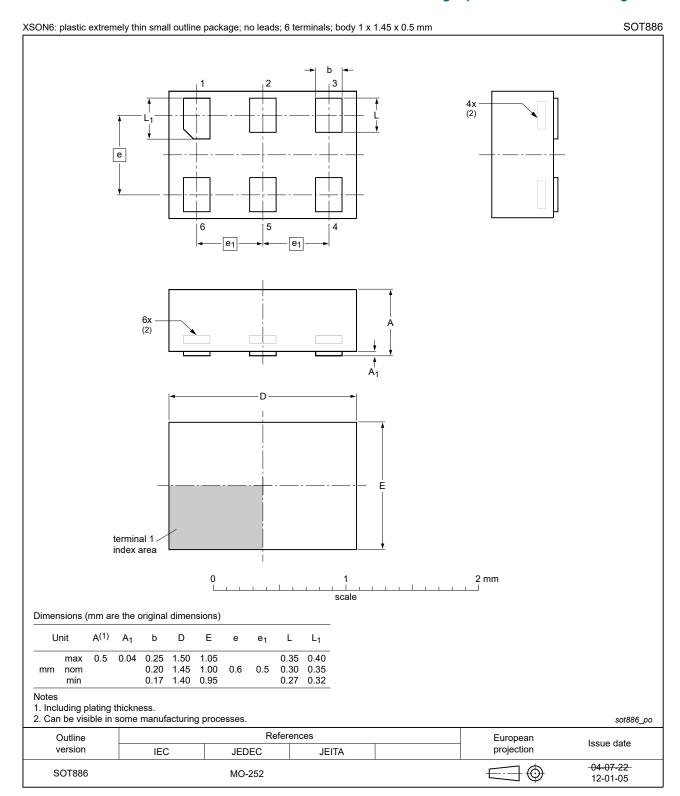


Fig. 22. Package outline SOT886 (XSON6)

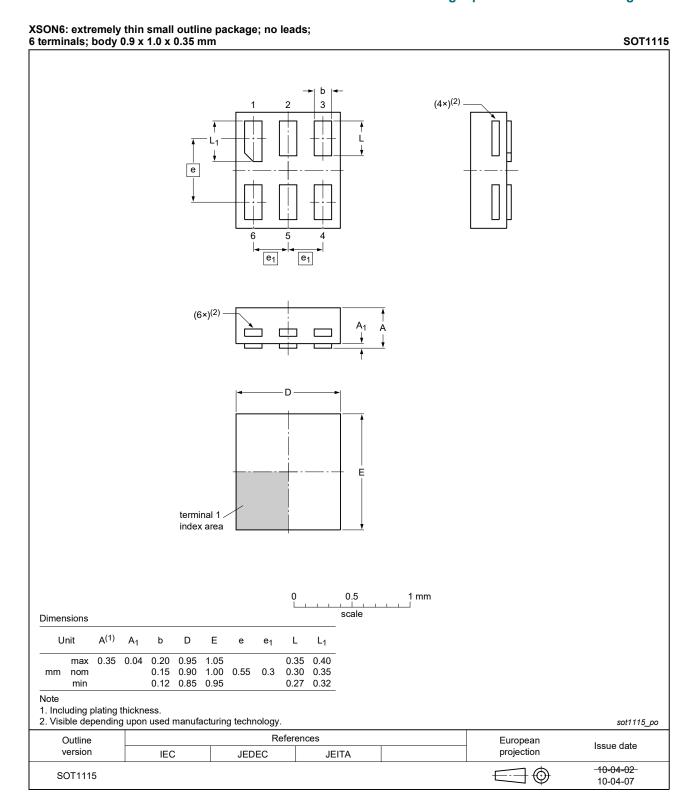


Fig. 23. Package outline SOT1115 (XSON6)

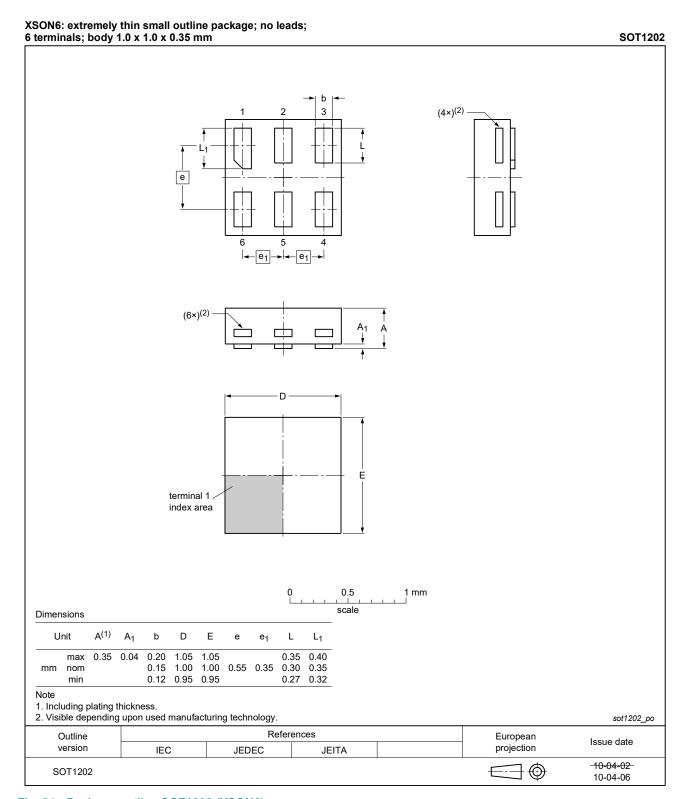


Fig. 24. Package outline SOT1202 (XSON6)

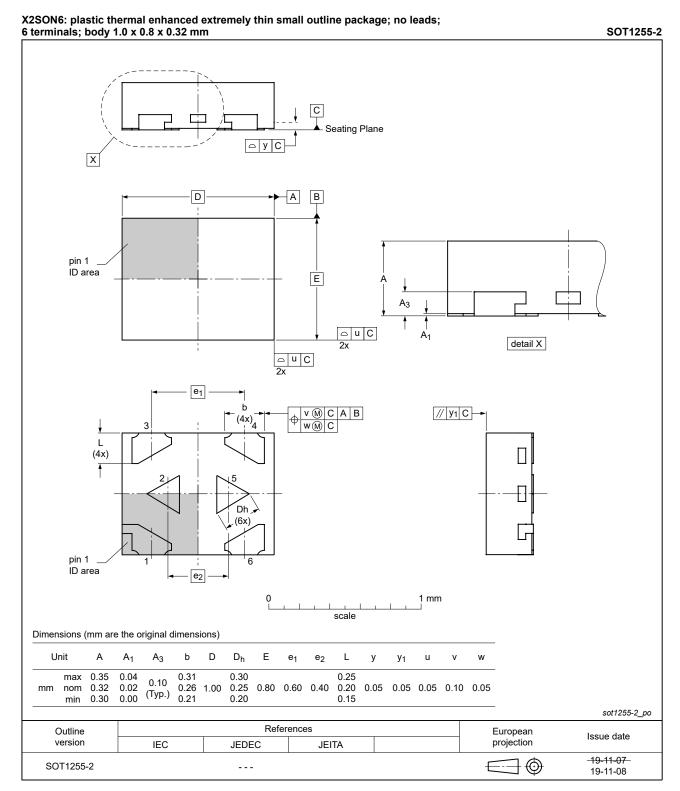


Fig. 25. Package outline SOT1255-2 (X2SON6)

10 Ω single-pole double-throw analog switch

13. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74LVC1G3157 v.11	20230823	Product data sheet	-	74LVC1G3157 v.10		
Modifications:	<u>Section 2</u> : ESD specification updated according to the latest JEDEC standard.					
74LVC1G3157 v.10	20230411	Product data sheet	-	74LVC1G3157 v.9		
Modifications:		ackage SOT1255 (X2SON6) changed to SOT1255-2 (X2SON6). odated descriptive title in line with 74LVC2G3157.				
74LVC1G3157 v.9	20230123	Product data sheet	-	74LVC1G3157 v.8		
Modifications:	Type numb	Type number 74LVC1G3157GF (SOT891/XSON6) removed.				
74LVC1G3157 v.8	20220204	Product data sheet	-	74LVC1G3157 v.7		
Modifications:	 Package SOT363 (SC-88) changed to SOT363-2 (TSSOP6). <u>Section 1</u> updated. <u>Table 5</u>: Derating values for P_{tot} total power dissipation updated. Package outline drawing <u>SOT457</u> updated. 					
74LVC1G3157 v.7	20170214	Product data sheet	-	74LVC1G3157 v.6		
Modifications:	 <u>Table 7</u>: The maximum limits for leakage current and supply current have changed. The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. 					
74LVC1G3157 v.6	20160512	Product data sheet	-	74LVC1G3157 v.5		
Modifications:	 Added type number 74LVC1G3157GX (SOT1255 package) Table 9: Minimum and maximum values enable and disable times revised. Table 12 and Fig. 17: Condition and test circuit for f_(-3dB) revised. Fig. 19: Test circuit for charge injection revised. 					
74LVC1G3157 v.5	20121206	Product data sheet	-	74LVC1G3157 v.4		
Modifications:	Package outline drawing of SOT886 (Fig. 22) modified.					
74LVC1G3157 v.4	20111206	Product data sheet	-	74LVC1G3157 v.3		
1 121 0 1 00 101 1.1						
74LVC1G3157 v.3	20100916	Product data sheet	-	74LVC1G3157 v.2		
	20100916 20070918	Product data sheet Product data sheet	-	74LVC1G3157 v.2 74LVC1G3157 v.1		

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal

10 Ω single-pole double-throw analog switch

injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by sustained.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

74LVC1G3157

All information provided in this document is subject to legal disclaimers.

© Nexperia B.V. 2023. All rights reserved

10 Ω single-pole double-throw analog switch

Contents

1. General description	1
2. Features and benefits	1
3. Ordering information	2
4. Marking	2
5. Functional diagram	2
6. Pinning information	3
6.1. Pinning	3
6.2. Pin description	3
7. Functional description	3
8. Limiting values	4
9. Recommended operating conditions	4
10. Static characteristics	5
10.1. Test circuits	5
10.2. ON resistance	6
10.3. ON resistance test circuit and graphs	7
11. Dynamic characteristics	9
11.1. Waveforms and test circuits	10
11.2. Additional dynamic characteristics	12
11.3. Test circuits	12
12. Package outline	14
13. Abbreviations	20
14. Revision history	20
15. Legal information	21

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 23 August 2023

[©] Nexperia B.V. 2023. All rights reserved

单击下面可查看定价,库存,交付和生命周期等信息

>>Nexperia(安世)